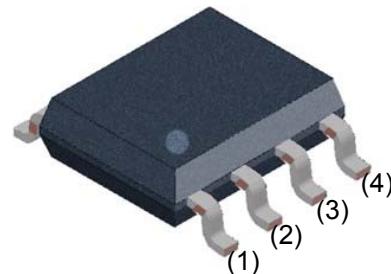


WCM2079

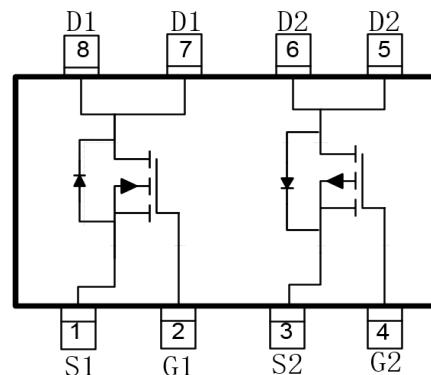
N- and P-Channel Complementary, 20V,MOSFET

<http://www.sh-willsemi.com>

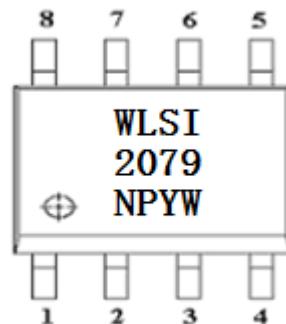
V_{DS} (V)	Typical R_{DS(on)} (Ω)
N-Channel	0.020@V _{GS} =10V
20	0.023@V _{GS} =4.5V
P-Channel	0.028@V _{GS} =-10V
-20	0.035@V _{GS} =-4.5V



SOP-8L



Pin configuration (Top View)



2079 = Device Code

NP = Special Code

YW = Date Code

Marking

Features

- Trench Technology
- Supper high density cell design
- Excellent ON resistance
- Extremely Low Threshold Voltage
- Package SOP-8L

Order Information

Device	Package	Shipping
WCM2079-8/TR	SOP-8L	4000/Tape&Reel

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	N-Channel		P-Channel		Unit		
		10 s	Steady State	10 s	Steady State			
V_{DSS}	Drain-to-Source Voltage	20		-20		V		
V_{GSS}	Gate-to-Source Voltage	± 20		± 20		V		
I_D	Continuous Drain Current ^{a d}	$T_A=25^\circ\text{C}$	6.5	5.1	-6.4	-5.0	A	
		$T_A=70^\circ\text{C}$	5.2	4.1	-5.1	-4.0		
P_D	Power Dissipation ^{a d}	$T_A=25^\circ\text{C}$	1.9	1.2	1.8	1.1	W	
		$T_A=70^\circ\text{C}$	1.2	0.8	1.1	0.7		
I_D	Continuous Drain Current ^{b d}	$T_A=25^\circ\text{C}$	6.0	4.9	-5.9	-4.8	A	
		$T_A=70^\circ\text{C}$	4.8	3.9	-4.7	-3.8		
P_D	Power Dissipation ^{b d}	$T_A=25^\circ\text{C}$	1.6	1.1	1.5	1.0	W	
		$T_A=70^\circ\text{C}$	1.1	0.7	1.0	0.6		
I_{DM}	Pulsed Drain Current ^c	26		-25		A		
T_J	Operation junction temperature	-55 to 150				$^\circ\text{C}$		
T_L	Lead Temperature	260				$^\circ\text{C}$		
T_{stg}	Storage temperature range	-55 to 150				$^\circ\text{C}$		

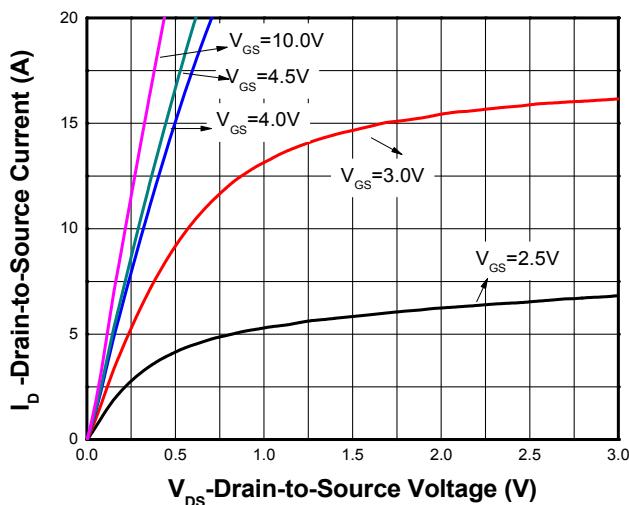
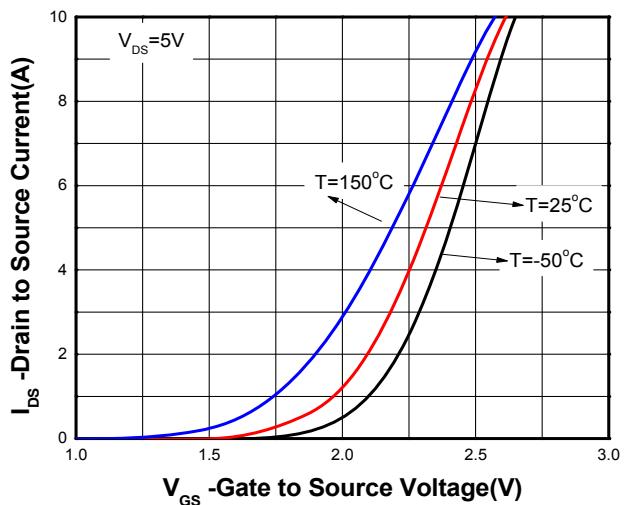
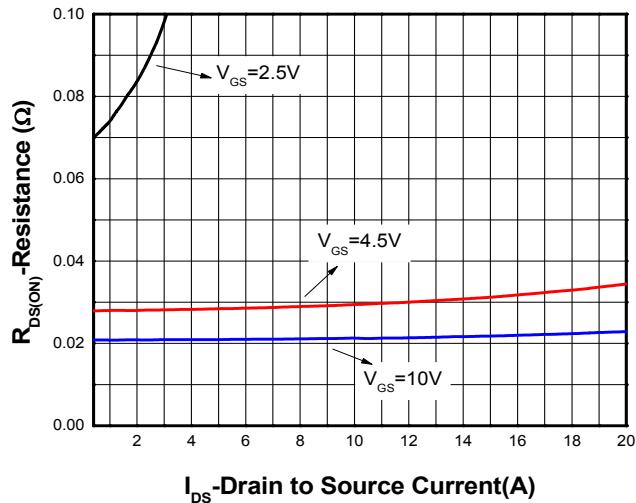
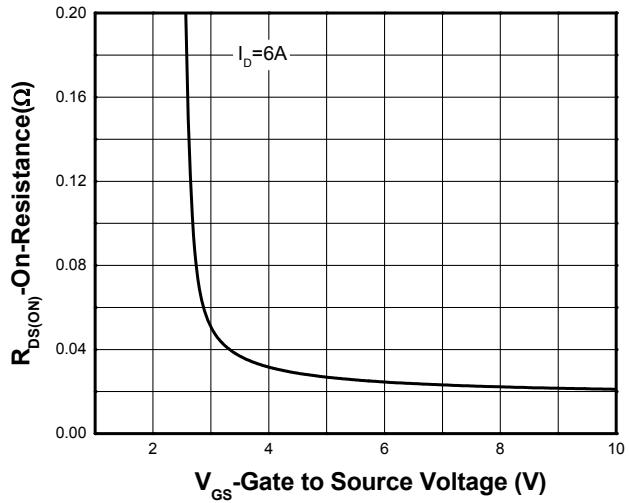
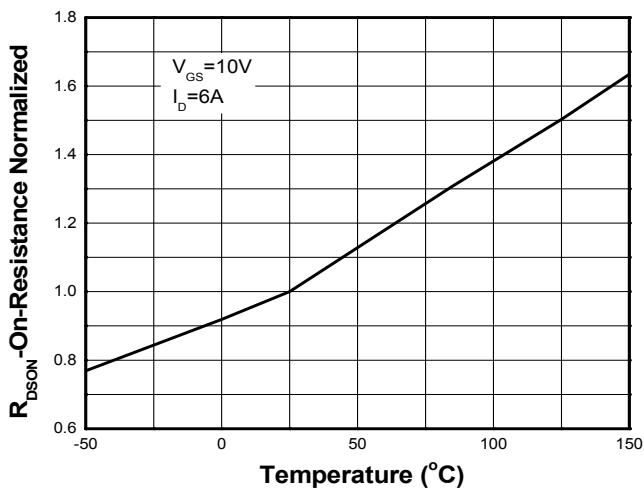
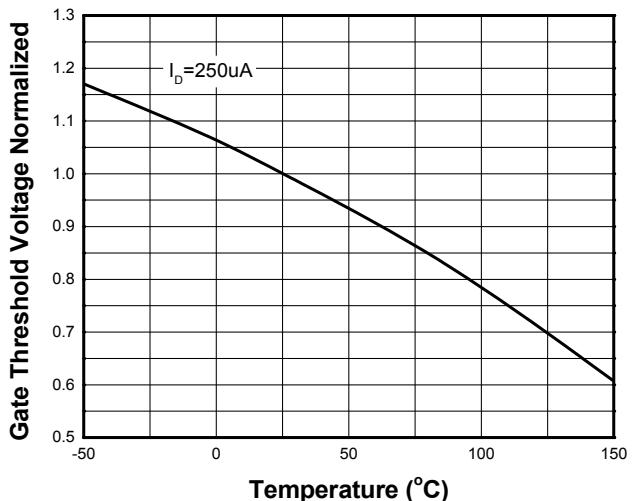
Thermal Resistance Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

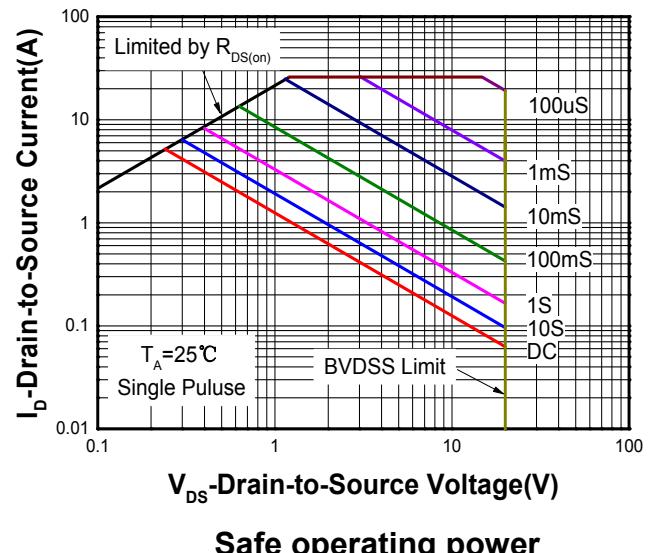
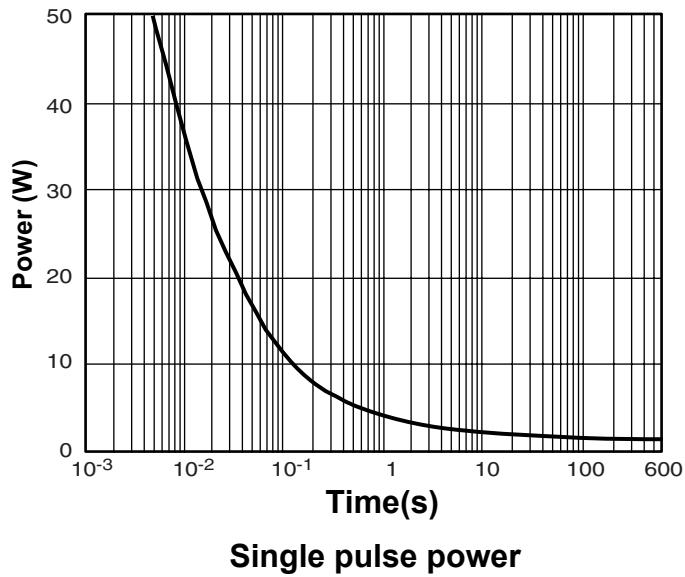
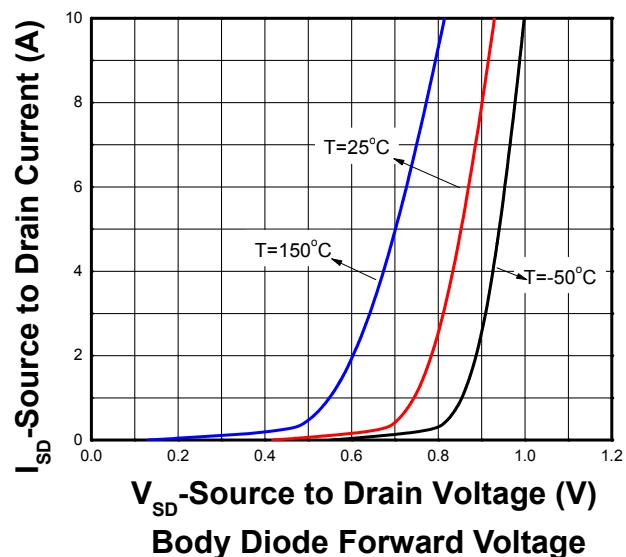
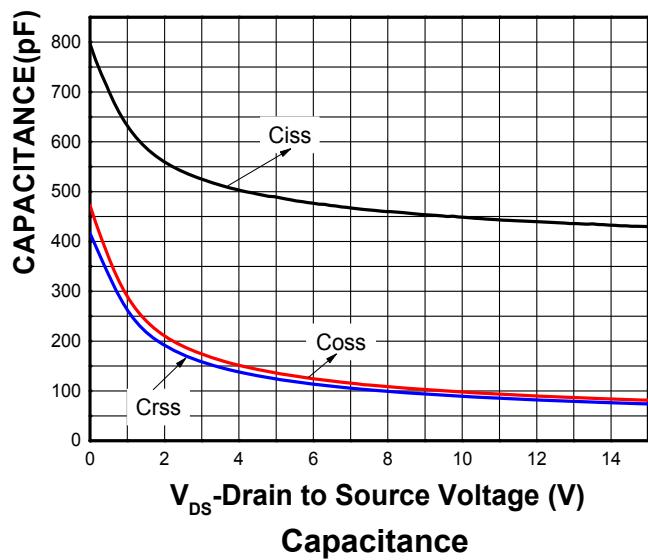
Parameter	Symbol	Typical	Maximum	Unit
Junction-to-Ambient Thermal Resistance ^a	$t \leq 10 \text{ s}$	$R_{\theta JA}$	56	65
	Steady State		87	105
Junction-to-Ambient Thermal Resistance ^b	$t \leq 10 \text{ s}$	$R_{\theta JA}$	64	76
	Steady State		96	115
Junction-to-Case Thermal Resistance	Steady State	$R_{\theta JC}$	32	40

- a Surface mounted on FR4 Board using 1 square inch pad size, 1oz copper
- b Surface mounted on FR4 board using minimum pad size, 1oz copper
- c Repetitive rating, pulse width limited by junction temperature, $tp=10\mu\text{s}$, Duty Cycle=1%
- d Repetitive rating, pulse width limited by junction temperature $T_J=150^\circ\text{C}$.

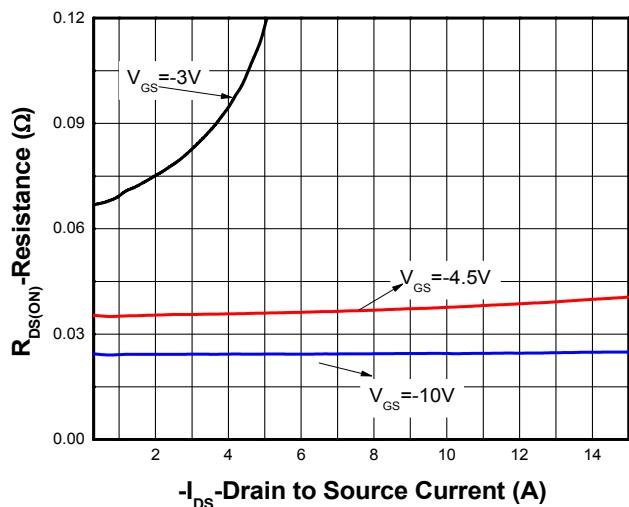
Electronics Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Test Condition		Min	Typ	Max	Unit	
Off Characteristics								
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	N-Ch	20			V	
		V _{GS} =0V, I _D =-250μA	P-Ch	-20				
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =16V, V _{GS} =0V	N-Ch			1	uA	
		V _{DS} =-16V, V _{GS} =0V	P-Ch			-1		
I _{GSS}	Gate –Source leakage current	V _{DS} =0V, V _{GS} =±20V	N-Ch			±100	nA	
			P-Ch			±100		
ON Characteristics								
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	N-Ch	1.0	1.5	2.5	V	
		V _{DS} =V _{GS} , I _D =-250μA	P-Ch	-1.0	-1.5	-2.5		
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V, I _D =6A	N-Ch		20	31	mΩ	
		V _{GS} =-10V, I _D =-5.5A	P-Ch		23	35		
		V _{GS} =4.5V, I _D =5.0A	N-Ch		28	41		
		V _{GS} =-4.5V, I _D =-5.0A	P-Ch		35	45		
Dynamic Characteristics								
C _{iss}	Input Capacitance	Nmos: V _{DS} =15V, V _{GS} =0V, f=1MHz Pmos: V _{DS} =-15V, V _{GS} =0V, f=1MHz	N-Ch		429		pF	
			P-Ch		1109			
C _{oss}	Output Capacitance		N-Ch		81			
			P-Ch		167			
C _{rss}	Reverse Transfer Capacitance		N-Ch		74			
			P-Ch		140			
t _{d(on)}	Turn-On Delay Time	Nmos: V _{DD} =5V, V _{GS} =4.5V, I _D =3.0A, R _G =3Ω Pmos: V _{DD} =-5V, V _{GS} =-4.5V, I _D =-3A, R _G =3Ω	N-Ch		12		ns	
			P-Ch		27			
t _r	Turn-On Rise Time		N-Ch		11			
			P-Ch		22			
t _{d(off)}	Turn-Off Delay Time		N-Ch		21			
			P-Ch		41			
t _f	Turn-Off Fall Time		N-Ch		10			
			P-Ch		24			
BODY DIODE CHARACTERISTICS								
V _{SD}	Forward Voltage	V _{GS} = 0 V, I _S = 1.0A	N-Ch		0.75	1.5	V	
		V _{GS} = 0 V, I _S = -1.0A	P-Ch		-0.75	-1.5		

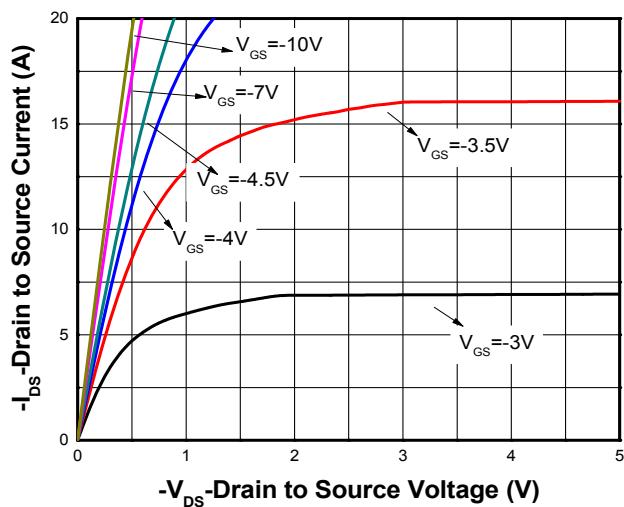
Typical Characteristics (N-Channel Ta=25°C, unless otherwise noted)

Output characteristics

Transfer characteristics

On-Resistance vs. Drain current

On-Resistance vs. Gate-to-source

On-Resistance vs. Junction temperature

Threshold voltage vs. Temperature



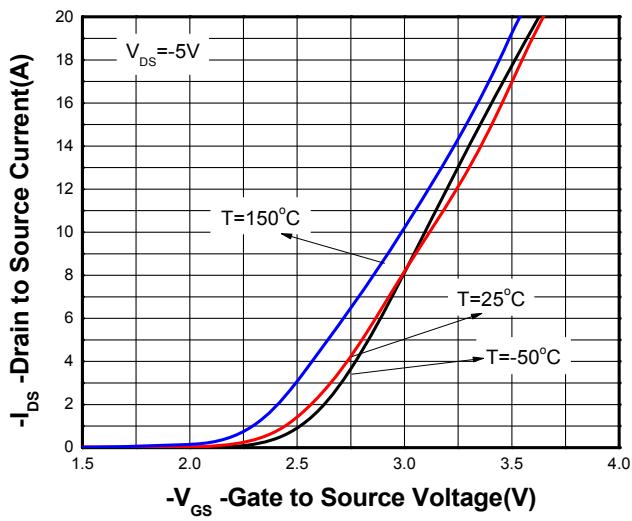
Typical Characteristics (P-Channel Ta=25°C, unless otherwise noted)



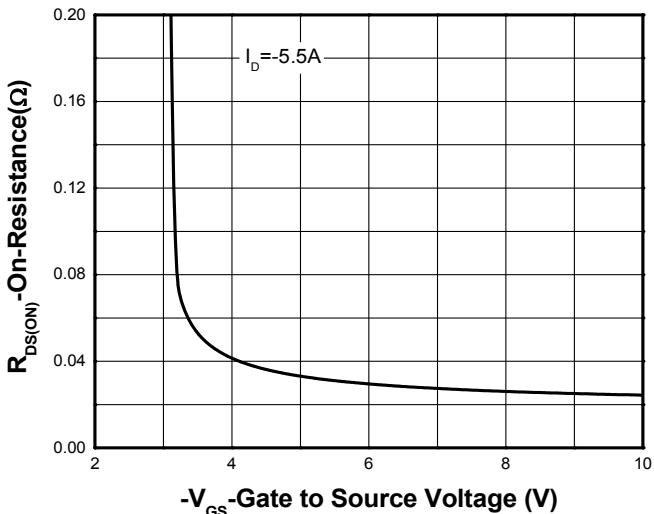
Output characteristics



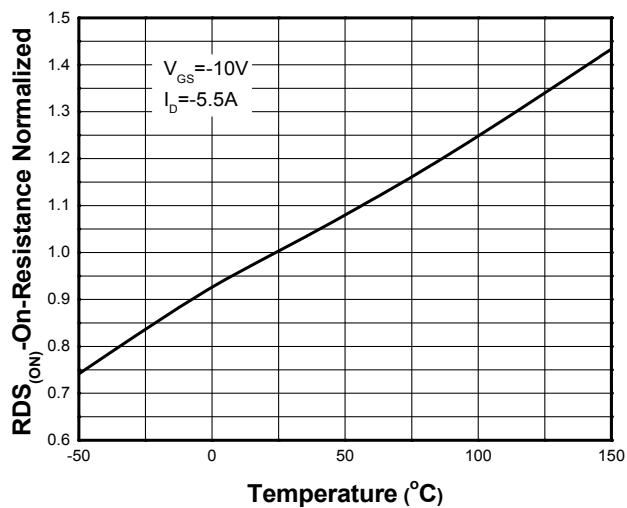
Transfer characteristics



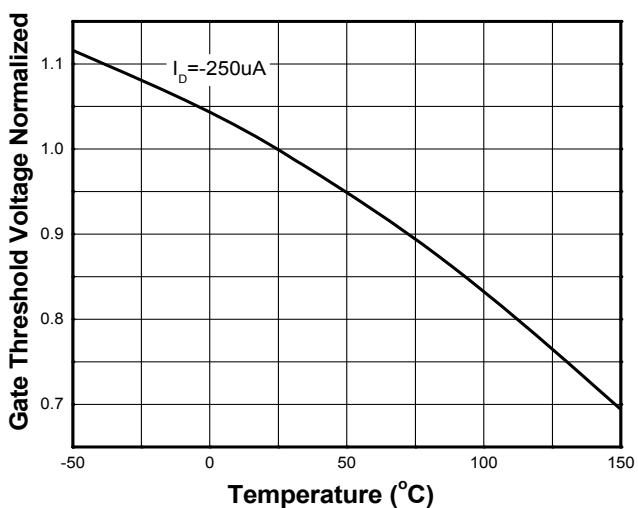
On-Resistance vs. Drain current



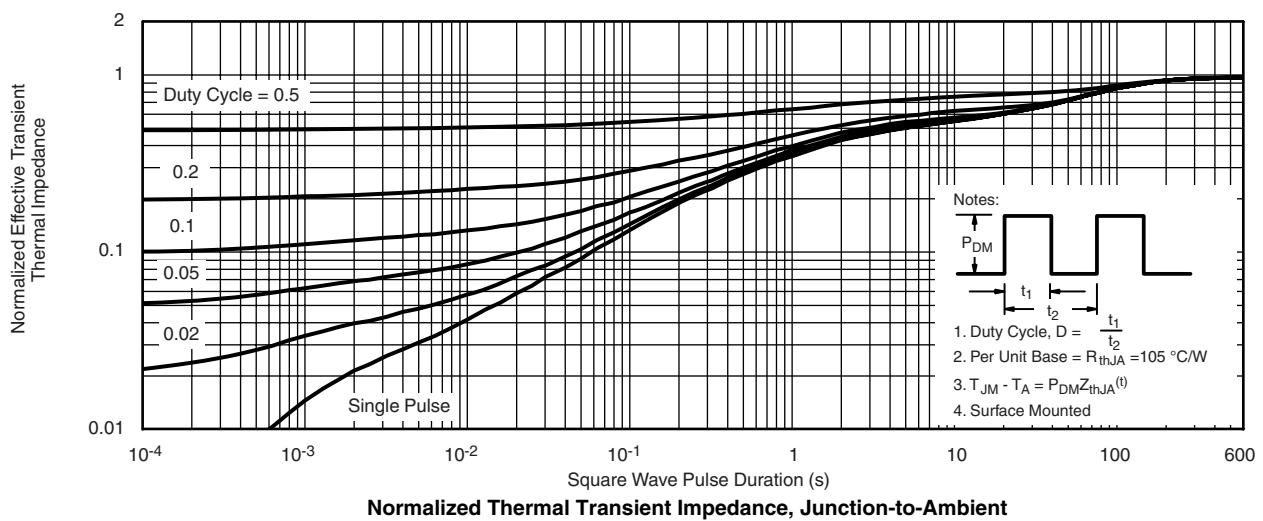
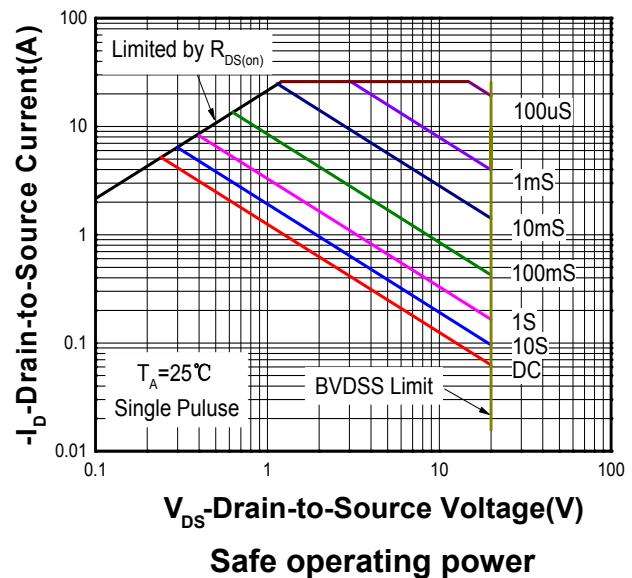
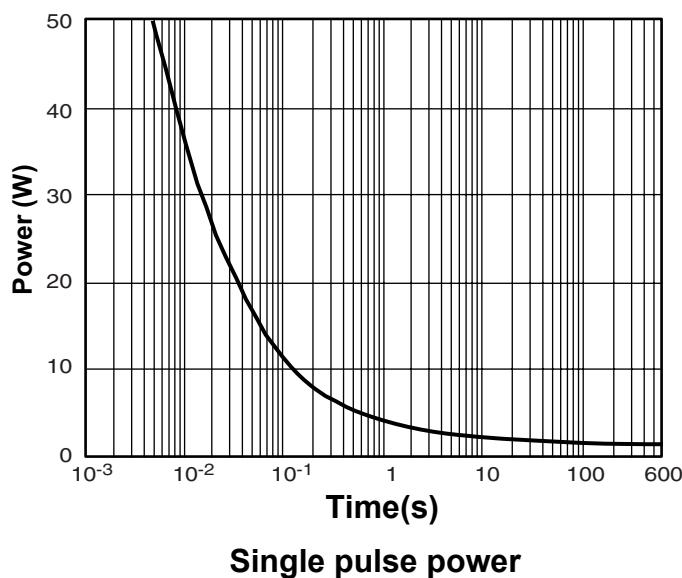
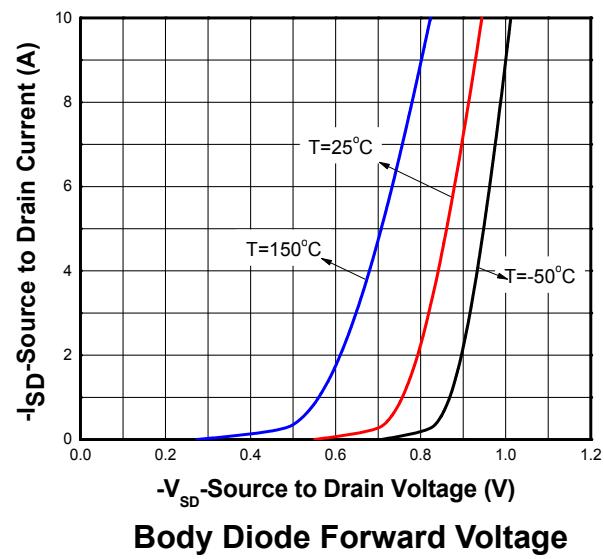
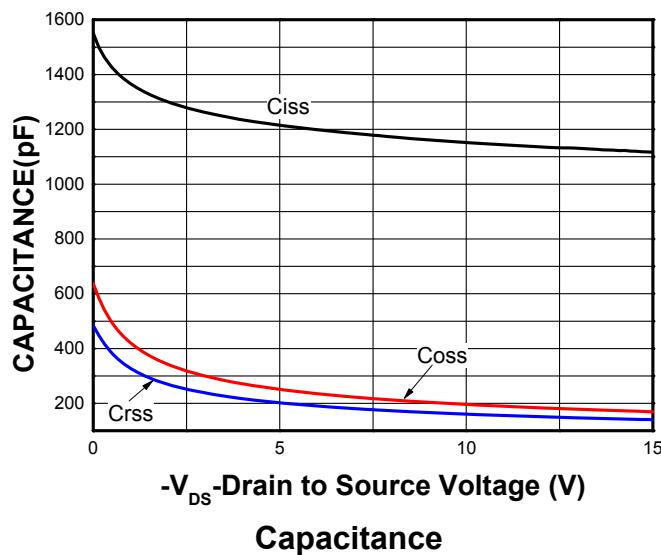
On-Resistance vs. Gate-to-source voltage

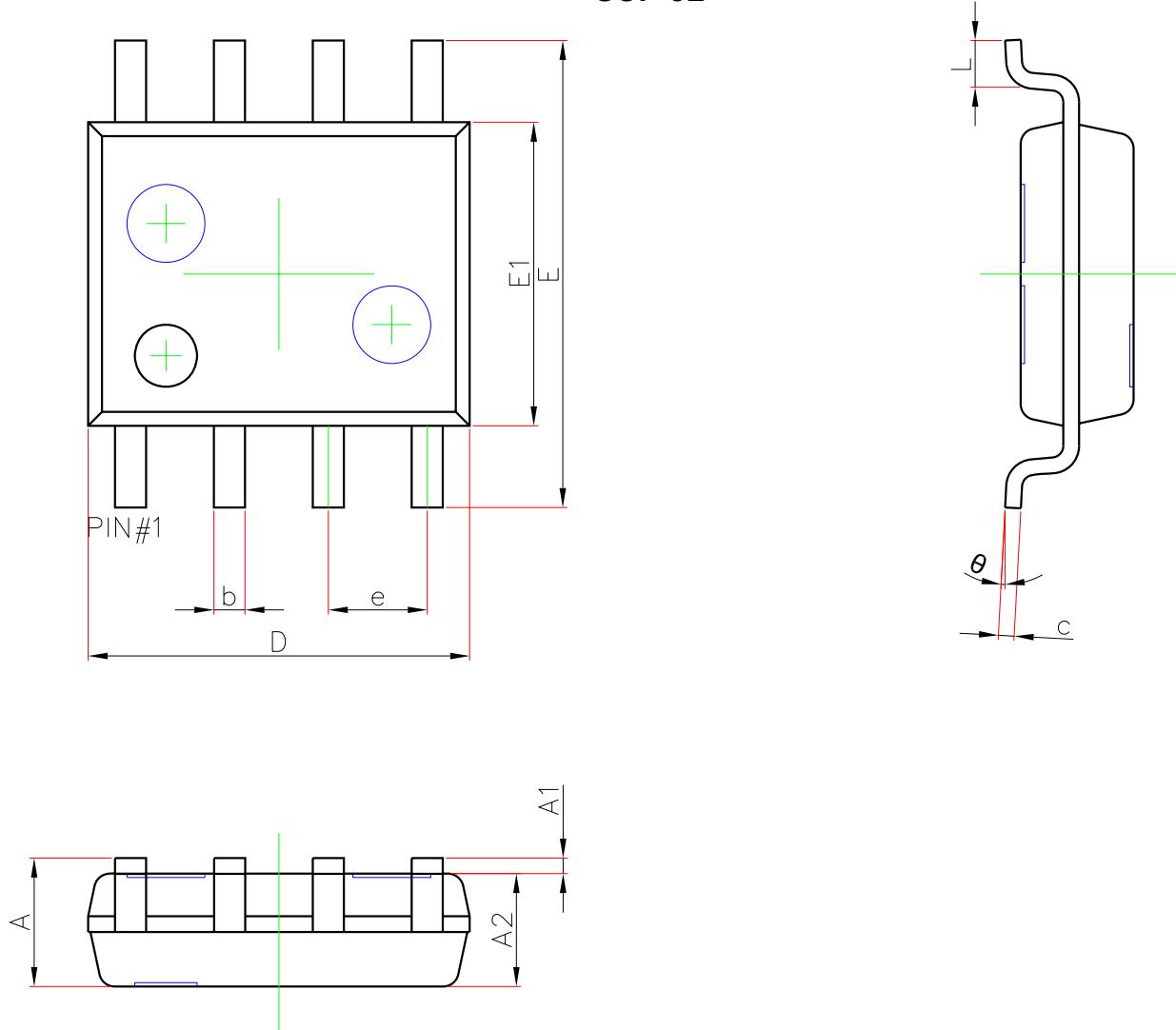


On-Resistance vs. Junction temperature



Threshold voltage vs. Temperature



Package outline dimensions
SOP-8L


Symbol	Dimensions in millimeter		
	Min.	Typ.	Max.
A	1.350	1.550	1.750
A1	0.100	0.175	0.250
A2	1.350	1.450	1.550
b	0.330	0.420	0.510
c	0.170	0.210	0.250
D	4.700	4.900	5.100
E	5.800	6.000	6.200
E1	3.800	3.900	4.000
e	1.270(BSC)		
L	0.400	0.600	0.800
θ	0°		8°

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